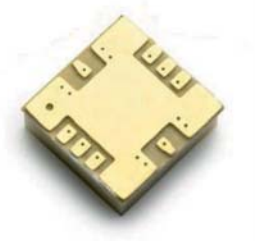
AMMP-6650
DC – 30 GHz Variable Attenuator

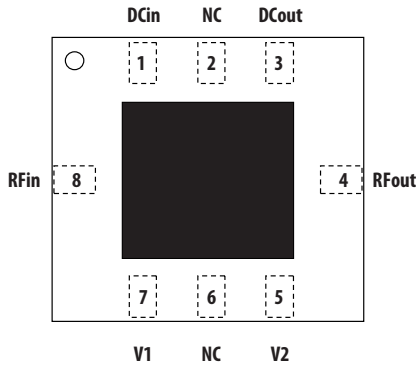
Data Sheet



Description

The AMMP-6650 is a voltage controlled variable attenuator in a surface mount package, designed to operate from DC to 30 GHz. It is fabricated using Avago Technologies enhancement mode pHEMT MMIC process and requires only positive voltage control. The distributed topology of the AMMP-6650 facilitates broadband operation by absorbing parasitic effects of its series and shunt FETs. An on-chip DC reference circuit may be used to maintain optimum VSWR for any attenuation setting or to provide more linear attenuation versus voltage response.

Package Diagram



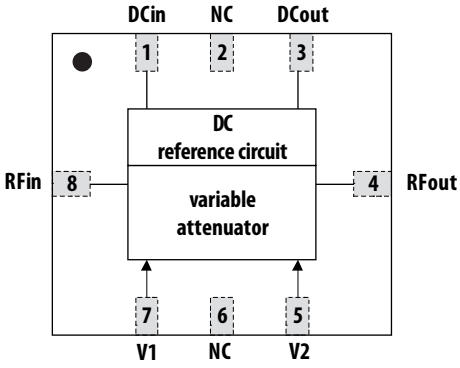
Features

- 5 x 5 mm Surface Mount Package
- Wide Frequency Range DC - 30 GHz
- Attenuation Range 20dB
- Single Positive Bias Supply
- Unconditionally Stable

Applications

- Microwave Radio Systems
- Satellite VSAT, DBS Up / Down Link
- LMDS & Pt – Pt mmW Long Haul
- Broadband Wireless Access (including 802.16 and 802.20 WiMax)
- WLL and MMDS loops

Functional Block Diagram



Top View

Pin	Function
1	DC in
2	NC
3	DC out
4	RF out
5	V2
6	NC
7	V1
8	RF in

Note : Package base : GND

RoHS-Exemption



Please refer to hazardous substances table on page 9.



Attention: Observe precautions for handling electrostatic sensitive devices.
ESD Machine Model = 80 V
ESD Human Body Model = 400 V
Refer to Avago Application Note A004R: Electrostatic Discharge, Damage and Control.

Note: MSL Rating = Level 2A

Electrical Specifications

1. Small/Large -signal data measured in a fully de-embedded test fixture form TA = 25°C.
2. Data obtained from on-wafer measurement
3. This final package part performance is verified by a functional test correlated to actual performance at one or more frequencies.
4. Specifications are derived from measurements in a 50 Ω test environment. Aspects of the amplifier performance may be improved over a more narrow bandwidth by application of additional conjugate, linearity, or low noise (Γopt) matching.

Table 1. RF Electrical Characteristics [1,2]

Symbol	Parameters and Test Conditions	Units	Freq. [GHz]	Minimum	Typical	Maximum
Minimum Attenuation (Reference State)	|S21| V1 = 1.5 V V2 = 0.0 V	dB	2		0.9	1.5
			10		2.0	2.5
			20		0.9	2.5
			30		2.1	3.0
Maximum Attenuation	|S21| V1 = 0.0 V V2 = 1.25 V	dB	2	23	26.6	
			10	23	28.0	
			20	23	30.0	
			30	23	35.6	
Return Loss (In/Out) at Reference State	V1=1.5 V, V2=0.0 V	dB	<30		10	
Return Loss (In/Out) at Max. Attenuation	V1=0.0 V, V2=1.25 V	dB	<30		10	

Table 2. Recommended Operating Range

1. Ambient operational temperature TA = 25°C unless otherwise noted.
2. Data obtained from on-wafer measurement

Parameter	Min.	Typical	Max.	Unit	Test Condition
V1 Control Current (Min Attenuation), Ic_V1_ref		1.93	2.0	mA	Vse=1.2V, Vsh=0
V2 Control Current (Min Attenuation), Ic_V2_ref		0.8	2.5	uA	Vse=0V, Vsh=1.2V
V1 Control Current (Max Attenuation), Ic_V1_max		1.1	2.5	uA	Vse=0V, Vsh=1.2V
V2 Control Current (Max Attenuation), Ic_V2_max		1.41	1.5	mA	Vse=1.2V, Vsh=0

Table 3. Absolute Minimum and Maximum Ratings [1]

Parameter	Min.	Max.	Unit	Comments
Voltage to Control VSWR, V1	0	1.6	V	
Voltage to Control Attenuation, V2	0	1.6	V	
RF Input Power, Pin		17	dBm	
Operating Channel Temperature, Tch		+150	dB	
Storage Temperature, Tstg	-65	+150	°C	
Maximum Assembly Temperature, Tmax		300	°C	60 second maximum

Notes:
1. Operation in excess of any one of these conditions may result in permanent damage to this device. The absolute maximum ratings for V1, V2 and Pin were determined at an ambient temperature of 25°C unless noted otherwise..

Typical Performance ($T_A = 25°C$, $Z_{in} = Z_{out} = 50\ \Omega$)

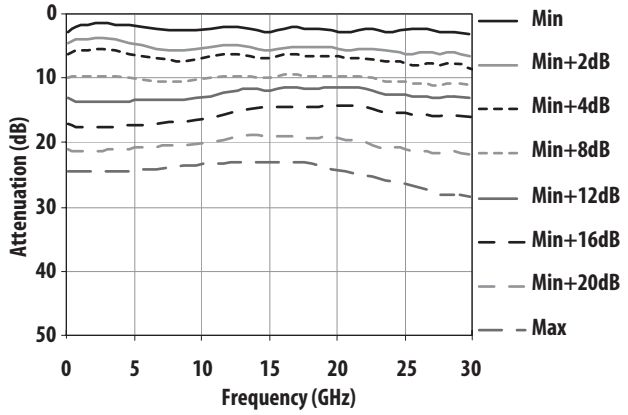


Figure 1. Attenuation vs Frequency

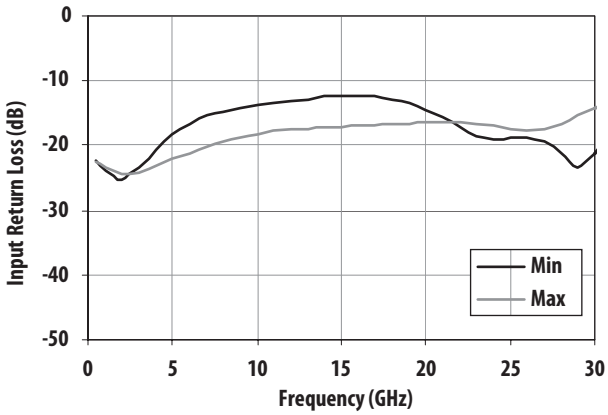


Figure 2. Input Return Loss vs Frequency

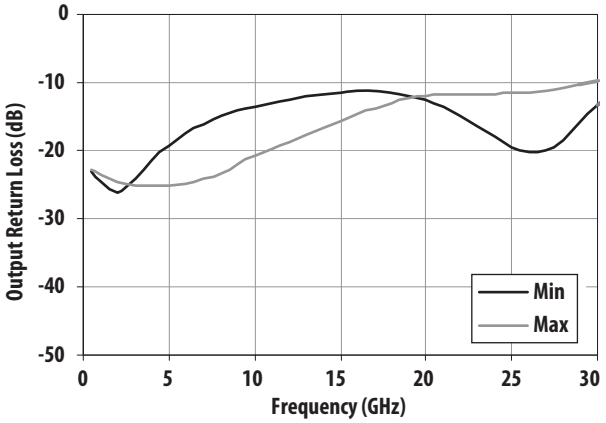


Figure 3. Output Return Loss vs Frequency

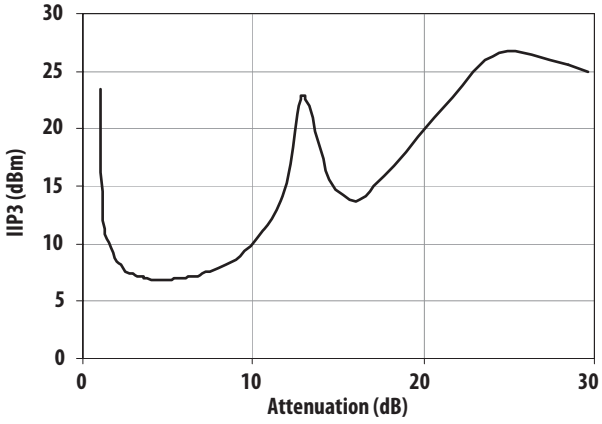


Figure 4. IIP3 vs Attenuation at 2 GHz (note 2)

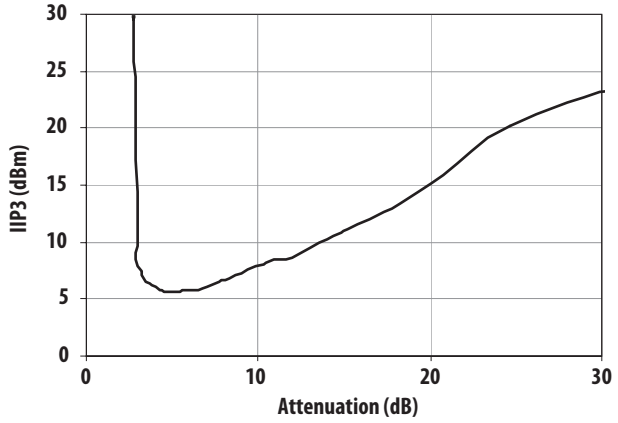


Figure 5. IIP3 vs Attenuation at 12 GHz (note 2)

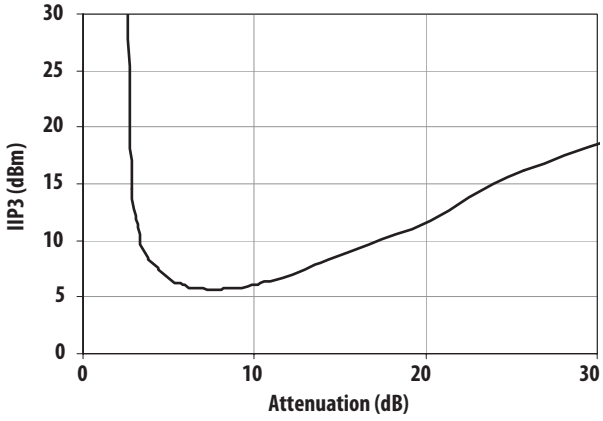


Figure 6. IIP3 vs Attenuation at 22 GHz (note 2)

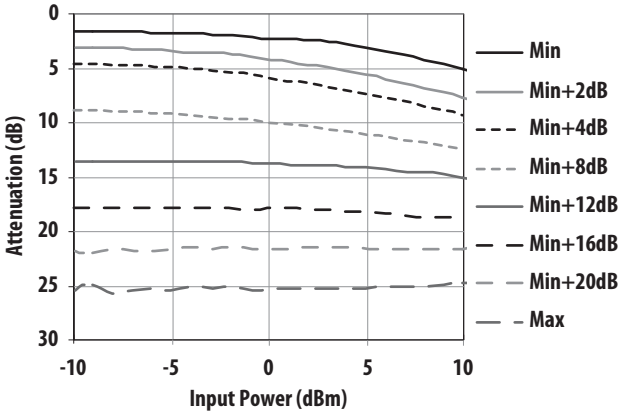


Figure 7. Attenuation vs Input Power at 2 GHz

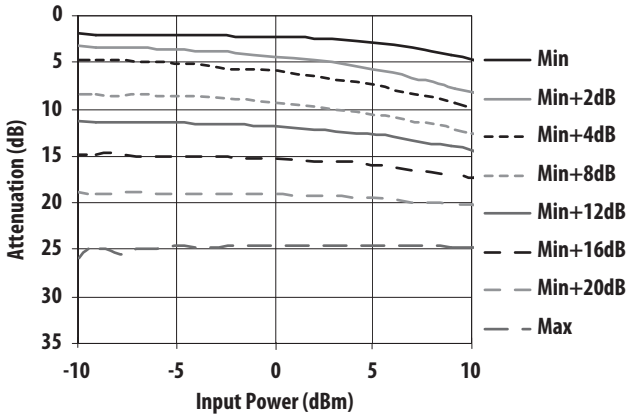


Figure 8. Attenuation vs Input Power at 12 GHz

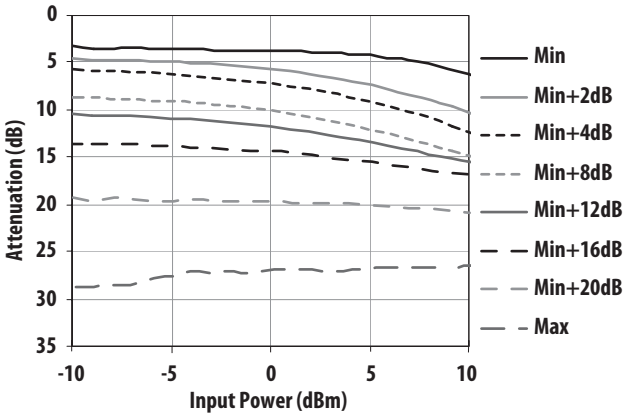


Figure 9. Attenuation vs Input Power at 22 GHz

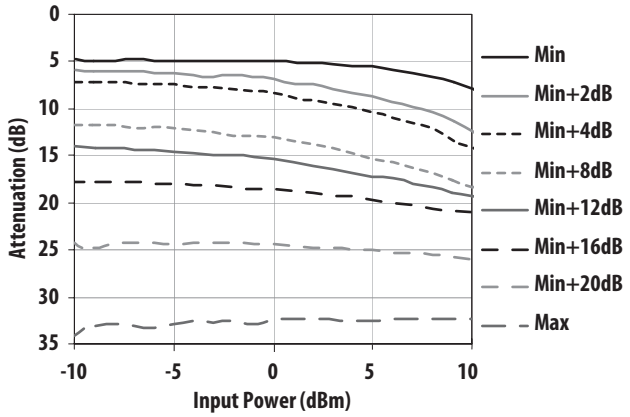


Figure 10. Attenuation vs Input Power at 32 GHz

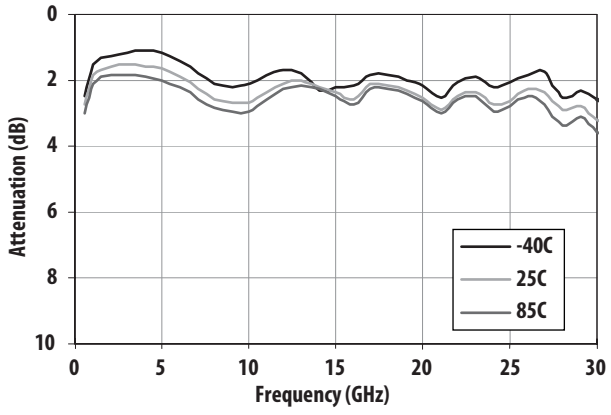


Figure 11. Attenuation vs Frequency (Min Attenuation)

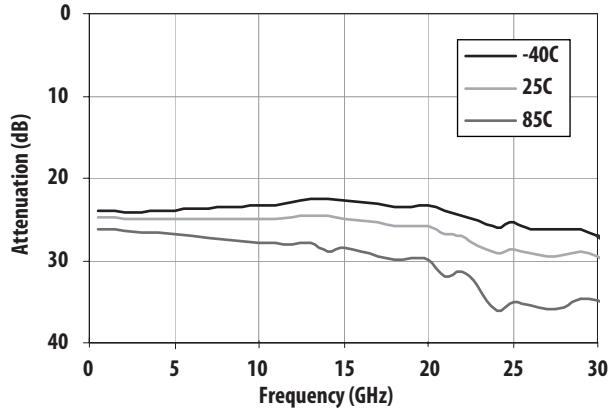


Figure 12. Attenuation vs Frequency (Max Attenuation)

Notes:
1. All tests done on an AMMP-6650 mounted on a PCB equipped with RF connectors and an op-amp driver shown in Figure 14.
2. IIP3 measured with two input signals with frequency difference of 10 MHz, each input signal at -10 dBm
3. All attenuation settings were done at 2GHz utilizing the AMMP-6650 DC Reference circuit. V_{REF} was set to 0.1 volt.

AMMP-6650 Typical Scattering Parameters at Minimum Attenuation

(Tc = 25°C, Zo = 50ohm, V_1 = 1.5V, V_2 = 0V)

Freq		S11			S21			S12			S22	
GHz	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase
0.5	-26.02	0.05	-39.1	-1.13	0.88	-5.8	-1.15	0.88	-5.8	-26.2	0.05	-39.2
1	-26.02	0.05	-66.7	-1.1	0.88	-10.3	-1.18	0.87	-10.3	-25.51	0.05	-60.2
2	-22.73	0.07	-93.5	-1.13	0.88	-19.2	-1.23	0.87	-19.2	-22.62	0.07	-85.5
3	-20.09	0.1	-108	-1.24	0.87	-28.1	-1.34	0.86	-28.1	-20.18	0.1	-102.1
4	-18.34	0.12	-120.3	-1.31	0.86	-36.9	-1.43	0.85	-36.9	-18.56	0.12	-115.4
5	-16.95	0.14	-131.5	-1.36	0.86	-45.5	-1.47	0.84	-45.5	-17.33	0.14	-127.6
6	-16.03	0.16	-140.9	-1.42	0.85	-54.2	-1.55	0.84	-54	-16.36	0.15	-137.4
7	-15.34	0.17	-149.7	-1.46	0.85	-62.7	-1.6	0.83	-62.5	-15.76	0.16	-146.5
8	-14.8	0.18	-157.5	-1.52	0.84	-71.3	-1.65	0.83	-71	-15.24	0.17	-155
9	-14.7	0.18	-165.3	-1.55	0.84	-79.8	-1.7	0.82	-79.5	-15.04	0.18	-163.3
10	-14.47	0.19	-172.9	-1.62	0.83	-88.4	-1.74	0.82	-88	-14.94	0.18	-171.8
11	-14.75	0.18	-180	-1.64	0.83	-96.8	-1.79	0.81	-96.5	-14.99	0.18	179.9
12	-14.85	0.18	172.5	-1.68	0.82	-105.4	-1.82	0.81	-105.1	-15.34	0.17	172.3
13	-15.39	0.17	165.6	-1.7	0.82	-114.1	-1.84	0.81	-113.7	-15.81	0.16	164.3
14	-15.92	0.16	158.2	-1.73	0.82	-122.8	-1.85	0.81	-122.4	-16.42	0.15	156.6
15	-16.83	0.14	151	-1.76	0.82	-131.5	-1.87	0.81	-131.2	-17.33	0.14	148.6
16	-17.86	0.13	143.5	-1.78	0.82	-140.3	-1.88	0.81	-139.9	-18.64	0.12	141.1
17	-19.33	0.11	135.1	-1.8	0.81	-149.3	-1.89	0.8	-148.9	-20.18	0.1	134
18	-21.11	0.09	127.3	-1.81	0.81	-158.4	-1.92	0.8	-158	-22.16	0.08	125.4
19	-23.35	0.07	116.3	-1.83	0.81	-167.7	-1.94	0.8	-167.1	-24.88	0.06	118.4
20	-27.33	0.04	99.3	-1.86	0.81	-176.9	-1.96	0.8	-176.5	-28.64	0.04	107.6
21	-32.77	0.02	59.4	-1.92	0.8	173.5	-2.03	0.79	174	-35.39	0.02	81.1
22	-31.7	0.03	-19.1	-2	0.79	163.9	-2.09	0.79	164.4	-37.72	0.01	-23.8
23	-25.68	0.05	-54	-2.12	0.78	154.2	-2.21	0.78	154.7	-29.37	0.03	-61.8
24	-21.62	0.08	-71.5	-2.23	0.77	144.6	-2.35	0.76	145.2	-24.44	0.06	-73.2
25	-18.34	0.12	-85.7	-2.35	0.76	135.4	-2.45	0.75	136	-20.92	0.09	-85.7
26	-16.48	0.15	-100.6	-2.38	0.76	126.8	-2.5	0.75	127.3	-18.49	0.12	-98.5
27	-14.99	0.18	-114.3	-2.45	0.75	118.8	-2.56	0.75	119.2	-16.77	0.15	-111
28	-14.33	0.19	-127.7	-2.5	0.75	110.1	-2.59	0.74	110.6	-15.86	0.16	-123.6
29	-14.24	0.19	-137.9	-2.58	0.74	101.1	-2.64	0.74	101.6	-15.49	0.17	-134.6
30	-14.47	0.19	-147.1	-2.65	0.74	91.5	-2.69	0.73	91.9	-15.65	0.17	-144.9
31	-14.52	0.19	-155.5	-2.7	0.73	82.3	-2.72	0.73	82.8	-15.76	0.16	-151.7
32	-14.99	0.18	-164.2	-2.73	0.73	73.2	-2.77	0.73	73.8	-16.14	0.16	-160.2
33	-16.03	0.16	-171.7	-2.78	0.73	63.3	-2.83	0.72	63.9	-17.2	0.14	-168.8
34	-17.72	0.13	-177.3	-2.83	0.72	53.1	-2.88	0.72	53.7	-18.86	0.11	-174.7
35	-20.09	0.1	-178	-2.83	0.72	42.8	-2.93	0.71	43.3	-20.92	0.09	-173.1
36	-22.5	0.08	-166.3	-2.95	0.71	32	-2.96	0.71	32.7	-23.48	0.07	-162.3
37	-23.48	0.07	-143.6	-2.96	0.71	21	-3.01	0.71	21.8	-24.01	0.06	-137.3
38	-21.41	0.09	-122.9	-3.01	0.71	9.9	-3.09	0.7	10.6	-21.62	0.08	-117.7
39	-18.56	0.12	-116.9	-3.12	0.7	-1.5	-3.2	0.69	-0.7	-18.56	0.12	-113.5
40	-16.36	0.15	-118.7	-3.25	0.69	-13	-3.31	0.68	-12.2	-16.31	0.15	-115.9
41	-14.56	0.19	-123.8	-3.43	0.67	-24.9	-3.49	0.67	-24.1	-14.33	0.19	-122
42	-13.11	0.22	-130.9	-3.69	0.65	-36.8	-3.76	0.65	-36.1	-12.69	0.23	-130.4
43	-12.01	0.25	-139.4	-4.01	0.63	-48.7	-4.08	0.63	-48.2	-11.5	0.27	-139.5
44	-11.28	0.27	-148.9	-4.34	0.61	-60.5	-4.42	0.6	-59.7	-10.66	0.29	-149.8
45	-10.81	0.29	-158.8	-4.78	0.58	-72.7	-4.82	0.57	-71.9	-9.95	0.32	-160.7
46	-10.57	0.3	-169.5	-5.26	0.55	-84.2	-5.29	0.54	-83.5	-9.47	0.34	-171.9
47	-10.6	0.3	-179.7	-5.66	0.52	-95.7	-5.71	0.52	-95.1	-9.22	0.35	176.6
48	-10.78	0.29	170.4	-6.14	0.49	-107.7	-6.23	0.49	-107	-9.14	0.35	165
49	-11.28	0.27	162.1	-6.76	0.46	-119.1	-6.8	0.46	-118.5	-9	0.36	152.8

Notes:
AMMP-6650 mounted on a PCB equipped with RF connectors and an op-amp driver shown in Figure 14.

AMMP-6650 Typical Scattering Parameters at Maximum Attenuation

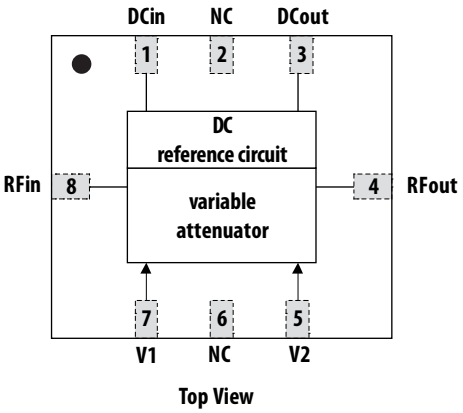
(Measured on-wafer, Tc = 25°C, Zo = 50ohm, V_1 = 0V, V_2 = 1.25V)

Freq		S11			S21			S12			S22	
GHz	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase	dB	Mag	Phase
0.5	-22.85	0.07	-12.3	-24.44	0.06	-3.8	-24.58	0.06	-3.7	-22.62	0.07	-12.7
1	-22.5	0.08	-21.6	-24.44	0.06	-6.7	-24.58	0.06	-6.7	-22.5	0.08	-21.4
2	-21.94	0.08	-38.5	-24.58	0.06	-12.6	-24.58	0.06	-12.7	-21.94	0.08	-38
3	-20.82	0.09	-53.4	-24.44	0.06	-18.5	-24.44	0.06	-18.5	-21.01	0.09	-53.6
4	-19.83	0.1	-67	-24.44	0.06	-24.6	-24.44	0.06	-24.7	-20.18	0.1	-66.8
5	-19.02	0.11	-78.6	-24.29	0.06	-30.8	-24.29	0.06	-30.8	-19.25	0.11	-78.9
6	-18.2	0.12	-89	-24.15	0.06	-37.1	-24.15	0.06	-37.2	-18.42	0.12	-89.1
7	-17.46	0.13	-98.9	-24.01	0.06	-44	-24.01	0.06	-43.8	-17.65	0.13	-98.2
8	-16.77	0.15	-107	-23.88	0.06	-51.1	-23.88	0.06	-50.9	-17.02	0.14	-107
9	-16.36	0.15	-114.6	-23.74	0.07	-58.5	-23.61	0.07	-58.5	-16.48	0.15	-115
10	-15.86	0.16	-121.5	-23.48	0.07	-66.2	-23.48	0.07	-66.1	-16.08	0.16	-122.5
11	-15.49	0.17	-127.9	-23.35	0.07	-74.1	-23.35	0.07	-74.1	-15.76	0.16	-129.7
12	-15.29	0.17	-134.6	-23.22	0.07	-82.4	-23.22	0.07	-82.3	-15.49	0.17	-136.5
13	-15.19	0.17	-140.7	-23.1	0.07	-91	-23.1	0.07	-90.9	-15.34	0.17	-142.7
14	-14.99	0.18	-146.6	-23.1	0.07	-100	-22.97	0.07	-100	-15.29	0.17	-149.2
15	-15.04	0.18	-151.7	-22.97	0.07	-109.5	-22.97	0.07	-109.6	-15.24	0.17	-154.9
16	-15.19	0.17	-156.8	-22.85	0.07	-119.4	-22.85	0.07	-119.4	-15.39	0.17	-160.4
17	-15.34	0.17	-162	-22.97	0.07	-130.1	-22.85	0.07	-130.1	-15.55	0.17	-165.3
18	-15.44	0.17	-166.1	-23.1	0.07	-141.6	-23.1	0.07	-141.7	-15.76	0.16	-169.3
19	-15.7	0.16	-170.4	-23.48	0.07	-153.4	-23.48	0.07	-153.2	-15.92	0.16	-172.9
20	-15.97	0.16	-174.7	-24.01	0.06	-164.8	-23.88	0.06	-164.8	-15.86	0.16	-176.5
21	-16.14	0.16	-178.9	-24.44	0.06	-174.2	-24.44	0.06	-174.2	-15.92	0.16	178.7
22	-16.48	0.15	176.4	-24.88	0.06	178.2	-24.88	0.06	178.2	-16.03	0.16	173.4
23	-16.95	0.14	170.7	-25.35	0.05	172.3	-25.19	0.06	172.3	-16.14	0.16	167.4
24	-17.52	0.13	166.5	-25.85	0.05	167.1	-25.68	0.05	167	-16.48	0.15	161.9
25	-18.06	0.13	164.2	-26.2	0.05	164.2	-26.2	0.05	163.9	-16.83	0.14	156.1
26	-18.64	0.12	159.6	-26.74	0.05	159.2	-27.13	0.04	159	-17.14	0.14	149.9
27	-19.33	0.11	154.9	-27.33	0.04	154	-27.54	0.04	153.4	-17.59	0.13	143.3
28	-19.66	0.1	149.9	-27.96	0.04	146.1	-27.74	0.04	145.7	-17.92	0.13	136.2
29	-20.54	0.09	144.5	-28.18	0.04	137.2	-28.18	0.04	137.1	-18.56	0.12	128.3
30	-21.62	0.08	135.2	-28.4	0.04	127.3	-28.4	0.04	126.5	-19.17	0.11	118.7
31	-22.73	0.07	126.4	-28.87	0.04	120.3	-28.87	0.04	120.3	-20	0.1	109.2
32	-24.01	0.06	118.1	-28.87	0.04	112.8	-28.87	0.04	112.6	-20.63	0.09	99.5
33	-25.51	0.05	103.6	-29.12	0.04	104	-29.12	0.04	103.2	-21.31	0.09	86.3
34	-26.94	0.05	81.6	-29.63	0.03	95.5	-29.37	0.03	95.1	-21.62	0.08	71.8
35	-27.54	0.04	58	-29.9	0.03	86.6	-29.9	0.03	86.3	-21.83	0.08	57.5
36	-27.13	0.04	33.7	-30.17	0.03	77.8	-30.17	0.03	77	-21.94	0.08	41.4
37	-25.85	0.05	12.4	-30.75	0.03	69.3	-30.75	0.03	70.4	-21.62	0.08	26.2
38	-23.88	0.06	-1.6	-31.06	0.03	61.3	-31.37	0.03	59.1	-21.01	0.09	12.2
39	-22.16	0.08	-16	-31.7	0.03	53.2	-31.7	0.03	53.8	-20.45	0.1	0.4
40	-20.35	0.1	-25.2	-32.04	0.03	45.6	-32.04	0.03	43.4	-19.66	0.1	-11.7
41	-19.25	0.11	-32.1	-32.4	0.02	36.2	-32.77	0.02	34.8	-18.79	0.12	-21.6
42	-17.92	0.13	-40.3	-33.15	0.02	27.5	-33.15	0.02	27.4	-18.2	0.12	-29.8
43	-17.14	0.14	-46.9	-33.98	0.02	18.7	-33.56	0.02	17.2	-17.86	0.13	-38
44	-16.42	0.15	-52.7	-34.42	0.02	10.3	-34.42	0.02	11.9	-17.27	0.14	-44.2
45	-15.76	0.16	-57	-34.89	0.02	-0.1	-35.39	0.02	-2.9	-16.89	0.14	-47.7
46	-15.04	0.18	-58	-35.92	0.02	-10	-35.92	0.02	-7.6	-16.65	0.15	-49
47	-14.29	0.19	-58.8	-36.48	0.02	-19.6	-36.48	0.02	-18.6	-15.92	0.16	-49.9
48	-13.47	0.21	-62.3	-37.72	0.01	-29.1	-37.72	0.01	-28.8	-14.7	0.18	-51
49	-12.04	0.25	-67.5	-38.42	0.01	-41.4	-37.72	0.01	-37.8	-13.56	0.21	-54.4

Notes:

AMMP-6650 mounted on a PCB equipped with RF connectors and an op-amp driver shown in Figure 14.

Biasing considerations



Pin	Function
1	DC in
2	NC
3	DC out
4	RF out
5	V2
6	NC
7	V1
8	RF in

Note : Package base : GND

Figure 13. Bias voltage connections

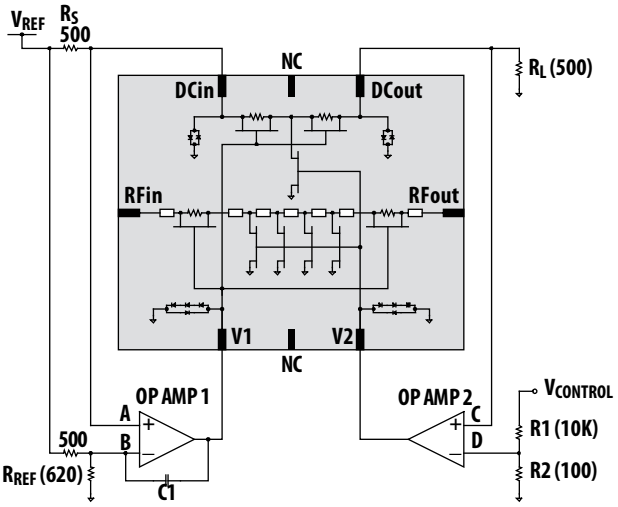


Figure 14. AMMP-6650 and the op-amp driver circuit

Attenuation is controlled by applying voltage to pin V1 (Pin 7) and pin V2 (Pin5), as shown in Figure 13.

For the minimum attenuation, V1 is set to 1.5 V and V2 is set to 0 V. The 1.5 V applied to the V1 pin biases the series FETs to a full "on" state, while the 0 V applied to the V2 pin keeps the shunt FETs in an "off" or "open" state; thus creating the lumped element 50 Ω transmission line effect. The V2 voltage swing from 0 V to 1.25 V increases the level of attenuation. The V1 voltage swing from 1.5 V to 0 V effectively optimizes the input and output match at higher attenuation levels. The AMMP-6650 can be driven by two complementary voltage ramps placed on V1 and V2. Careful adjustments of the two control lines over a relatively small voltage ranges are required to set the attenuation and optimize VSWR.

The on-chip DC reference circuit can be used to optimize VSWR for any attenuation setting, improve voltage versus attenuation linearity and range, and provide temperature compensation.

The on-chip DC reference circuit is a non-distributed "T" attenuator designed to operate in a 500 Ω system and track the control voltage versus attenuation characteristics of the RF attenuator. A simplified schematic of the AMMP-6650 together with an op-amp driver that utilizes the DC reference circuit is shown in Figure 14.

OP AMP 1 insures that the attenuator maintains a good input and output match to 50 Ω, while **OP AMP 2** increases the usable control voltage range versus using only direct voltage ramps for V1 and V2 and improves over temperature operation.

If optimum VSWR is all that is required, **OP AMP 2** may be eliminated however, R_L must remain connected to the DCout pad of the AMMP-6650 and the control voltage can be applied directly to V2.

CAUTION: Low voltage op-amps must be used so as not to exceed the maximum limit of V1 and V2 control voltages.

As shown, a voltage reference (V_{REF}) is fed to the reference circuit DCin pad via a 500 Ω resistor, creating a 500 Ω source. The reference circuit termination R_L, is connected to the DCout pad and ideally is also equal to 500 Ω. This voltage is controlled in parallel with the RF attenuator. The chosen value of V_{REF} must be low enough to avoid modifying the FET biasing and lower than the turn-on voltage of the ESD protection diode but high enough such that the attenuated voltage at **OP AMP 2** is usable compared to input offsets etc. The optimum value for the positive reference voltage is approximately 0.1 to 0.4 V.

At equilibrium, the voltages at nodes A and B of the **OP AMP 1** must be equal which implies that the input impedance to the DC reference circuit is equal to R_{REF}. When V2 is changed to a lower value, the voltage at node A becomes greater than that of node B. This voltage difference causes the output voltage of op **OP AMP 1** to move toward its positive rail until equilibrium is once again established. When V2 is changed to a higher value the voltage at node A becomes less than that of node B and the output voltage of **OP AMP 1** will swing toward its negative rail until equilibrium is reached. If the reference circuit precisely tracks the RF circuit, the voltage output of **OP AMP 1** at equilibrium insures that the RF circuit is matched to 50 Ω.

If attenuation linearity is required, **OP AMP 2** is included as shown in Figure 14 and a positive control voltage is applied to $V_{CONTROL}$. At equilibrium, voltages at nodes C and D are equal. When $V_{CONTROL}$ is changed, the output of **OP AMP 2** adjusts to a value that forces the voltage at node C to equal the voltage at node D. Therefore, the output voltage of the DC reference circuit is proportional to $V_{CONTROL}$. The input voltage to the reference circuit is being held constant and the log($V_{CONTROL}$) is proportional to the reference circuit attenuation 20log(DCout/DCin).

If the FET parameters of the DC reference circuit track the FET parameters of the RF circuit, the voltage output of the RF circuit is also proportional to the control voltage. This translates to a linear relationship between the attenuation (in dB) and the log($V_{CONTROL}$).

Two RF attenuation vs voltage curves corresponding to different values of V_{REF} are shown in Figure 15. These curves were obtained by using the driver circuit shown in Figure 14 and the V_{REF} values 0.1 V and 0.4 V. Values for R_L, R1 and R2 were 500 Ω, 10 kΩ and 100 Ω respectively. Control voltage ranged from 4.5 V to 0 V.

Because the FETs in the DC circuit are not identical to those in the RF circuit, the DC circuit does not exactly track the RF circuit. This results in attenuation vs. voltage curves that are not exactly linear.

OP AMP 2 provides temperature compensation by adjusting V2 in such a way as to keep voltage at point C equal to that point D. If the attenuation changes over temperature, voltage at point C tries to change, but is corrected by **OP AMP 2**.

Another way to improve performance of the attenuator driver circuit is to adjust R_L and R_{REF}. If the reference circuit precisely tracked the RF circuit and the ON resistance of the FETs was zero ohms, then R_L and R_{REF} would be exactly 500 Ω.

Due to the difference in layout structures, the reference circuit does not track the RF circuit precisely. R_L and R_{REF} can be adjusted in order to compensate for these differences. Optimum values of R_L and R_{REF} have been found to be between 500 Ω and 650 Ω.

For maximum dynamic range on the attenuation control circuit, R_L should be less than R_{REF} by an amount equal to the "ON resistance" of the reference circuit series FETs. The "ON resistance" of the series FETs is about 95 Ω total. Therefore, the relationship between R_L and R_{REF} is as follows:

$$R_{REF} = R_L + 95\ \Omega$$

The voltage divider formed by R1 and R2 can be used to adjust the sensitivity of the attenuator versus control voltage. For the driver circuit shown in Figure 14, maximum attenuation is always achieved by setting $V_{CONTROL}$ equal to 0 V. Minimum attenuation is achieved when

$$V_{control} \approx \left(\frac{R1 + R2}{R2}\right) x \left(\frac{R_L}{500\ \Omega + R_L}\right) x\, V_{ref}$$

or

$$V_{control} \approx \left(1 + \frac{R1}{R2}\right)\ x\ DC_{out}$$

Therefore, an increase in the resistor ratio R1/R2 increases the value of the control voltage required to produce minimum attenuation.

LMV932 (National Semiconductor) was used in the control circuit that produced the results shown in Figure 15; however, any low noise, low offset voltage op amp should produce similar results. LMV932's low supply voltage of 1.8 volts, limits the possibility of exceeding the 1.5 volt absolute maximum of the AMMC-6650 V1 and V2 control line inputs.

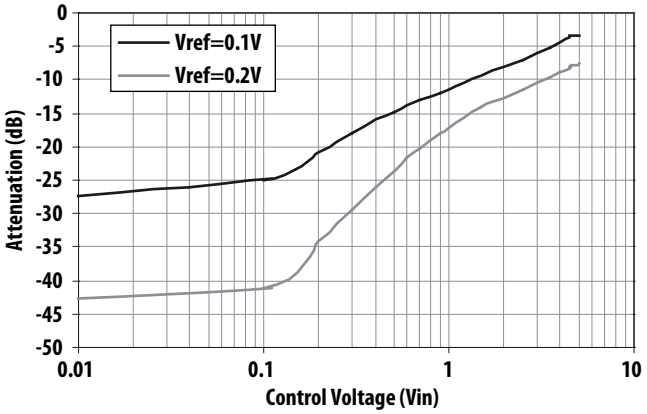


Figure 15. Attenuation vs. Control Voltage @ 15 GHz

Package Dimension, PCB Layout and Tape and Reel information

Please refer to Avago Technologies Application Note 5520, AMxP-xxxx production Assembly Process (Land Pattern A).

Ordering Information

Part Number	Devices Per Container	Container
AMMP-6650-BLKG	10	Antistatic bag
AMMP-6650-TR1G	100	7" Reel
AMMP-6650-TR2G	500	7" Reel



Names and Contents of the Toxic and Hazardous Substances or Elements in the Products
产品中有毒有害物质或元素的名称及含量

Part Name 部件名称	Toxic and Hazardous Substances or Elements 有毒有害物质或元素					
	Lead (Pb) 铅 (Pb)	Mercury (Hg) 汞 （Hg ）	Cadmium (Cd) 镉 （Cd ）	Hexavalent (Cr(VI)) 六价铬（Cr(VI) ）	Polybrominated biphenyl (PBB) 多溴联苯（PBB ）	Polybrominated diphenylether (PBDE) 多溴二苯醚（PBDE ）
100pF capacitor	×	O	O	O	O	O

O: indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006.
×: indicates that the content of the toxic and hazardous substance in at least one homogeneous material of the part exceeds the concentration limit requirement as described in SJ/T 11363-2006.
(The enterprise may further explain the technical reasons for the "x" indicated portion in the table in accordance with the actual situations.)

O：表示该有毒有害物质在该部件所有均质材料中的含量均在 SJ/T 11363-2006 标准规定的限量要求以下。
×：表示该有毒有害物质至少在该部件的某一均质材料中的含量超出 SJ/T 11363-2006 标准规定的限量要求。
（企业可在此处，根据实际情况对上表中打"×" 的技术原因进行进一步说明。）

Note: EU RoHS compliant under exemption clause of "lead in electronic ceramic parts (e.g. piezoelectronic devices)"

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AV02-1337EN - August 19, 2011

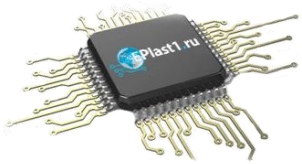
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- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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